



A Product Line of Diodes Incorporated



DMN2300U

20V N-CHANNEL ENHANCEMENT MODE MOSFET IN SOT23

Product Summary

V _{(BR)DSS}	R _{DS(on)}	I _D Max (Note 5)
	175mΩ @ V_{GS} = 4.5V	1.40A @ T _A = 25°C
20V	240m Ω @ V _{GS} = 2.5V	1.20A @ T _A = 25°C
	$360m\Omega @ V_{GS} = 1.8V$	1.0A @ T _A = 25°C

Description and Applications

This MOSFET has been designed to minimize the on-state resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Load switch

Features and Benefits

- On resistance <200mΩ
- Low Gate Threshold Voltage
- Fast Switching Speed
- "Lead Free", RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- ESD Protected Gate 2kV
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

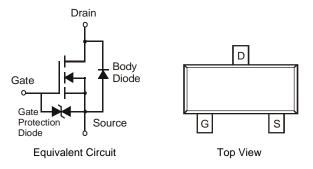
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin
- Weight: 0.08 grams (approximate)





SOT23

Top View



Ordering Information (Note 3)

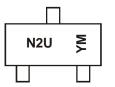
Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMN2300U-7	N2U	7	8	3000

Notes: 1. No purposefully added lead

2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com.

3. For packaging details, go to our website at http://www.diodes.com.

Marking Information



 $\begin{array}{l} \mathsf{N2U}=\mathsf{Product}\ \mathsf{Type}\ \mathsf{Marking}\ \mathsf{Code}\\ \mathsf{YM}=\mathsf{Date}\ \mathsf{Code}\ \mathsf{Marking}\\ \mathsf{Y}=\mathsf{Year}\ (\mathsf{ex}:\mathsf{Y}=\mathsf{2011})\\ \mathsf{M}=\mathsf{Month}\ (\mathsf{ex}:\mathsf{9}=\mathsf{September}) \end{array}$

Date Code Key

Date Obuc Rey												
Year	201	1	2012		2013	20	14	2015		2016	2	2017
Code	Y		Z		А	l	3	С		D		E
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D





DMN2300U

Maximum Ratings @T_A = 25°C unless otherwise specified

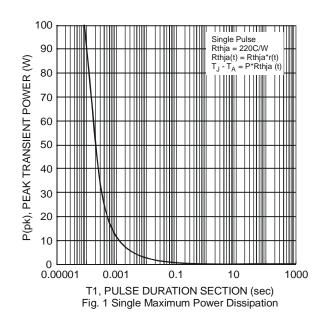
Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±8	V
Continuous Drain Current	Steady State	$T_A = 25^{\circ}C$ (Note 5) $T_A = 85^{\circ}C$ (Note 5) $T_A = 25^{\circ}C$ (Note 4)	ID	1.40 1.01 1.24	А
Pulsed Drain Current (Note 6)			I _{DM}	11	A

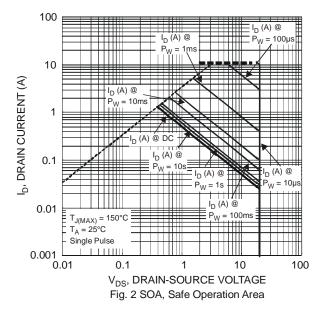
Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Characteristic			Unit
Power Dissipation	(Note 4)		0.43	W
	(Note 5)	P _D 0.55		W
Thermal Desistance Junction to Ambient	(Note 4)	P	288	°C/W
Thermal Resistance, Junction to Ambient	(Note 5)	R _{0JA}	228	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

4. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout Notes: 5. Device mounted on 25mm X 25mm square copper plate with FR-4 substrate PC board, 2oz copper 6. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.

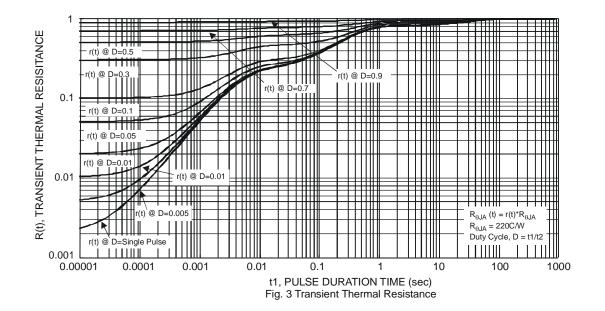
Thermal Characteristics











Electrical Characteristics @T_A = 25°C unless otherwise specified

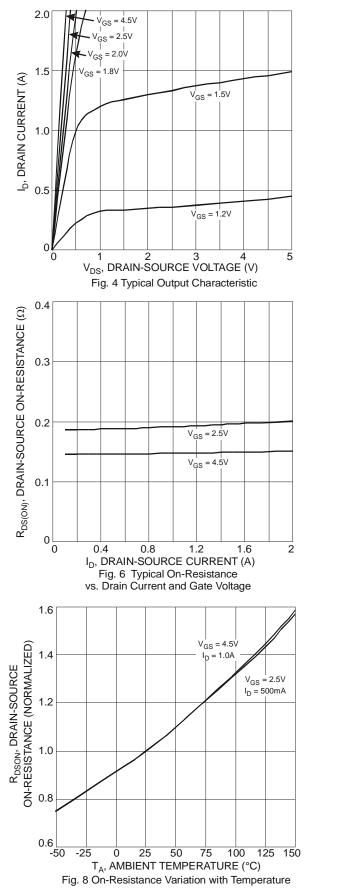
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	20	-	-	V	$V_{GS} = 0V, I_D = 10\mu A$
Zero Gate Voltage Drain Current T _J = 25°C	I _{DSS}	-	-	1	μΑ	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	-	-	10	μΑ	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)			-			
Gate Threshold Voltage	V _{GS(th)}	0.45	-	0.95	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
				175		$V_{GS} = 4.5V, I_D = 300mA$
Static Drain-Source On-Resistance	R _{DS (ON)}	-		240	mΩ	$V_{GS} = 2.5V, I_D = 250mA$
				360		$V_{GS} = 1.8V, I_D = 100mA$
Forward Transfer Admittance	Y _{fs}	40	-	-	mS	$V_{DS} = 3V$, $I_D = 30mA$
Diode Forward Voltage	V _{SD}	-	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 300mA$
DYNAMIC CHARACTERISTICS (Note 7)						_
Input Capacitance	C _{iss}	-	64.3	-	pF	
Output Capacitance	C _{oss}	-	6.1	-	pF	−V _{DS} = 25V, V _{GS} = 0V, −f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	-	4.5	-	pF	1 = 1.00012
Gate Resistance	R _g	-	70	-	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge	Qg	-	1.6	-	nC	
Gate-Source Charge	Q _{gs}	-	0.2	-	nC	−V _{GS} = 4.5V, V _{DS} = 15V, −I _D = 1A
Gate-Drain Charge	Q _{gd}	-	0.2	-	nC	ID = IA
Turn-On Delay Time	t _{D(on)}	-	3.5	-	ns	
Turn-On Rise Time	tr	-	2.8	-	ns	$V_{DS} = 10V, I_D = 1A$
Turn-Off Delay Time	t _{D(off)}	-	38	-	ns	V_{GS} = 10V, R_G = 6 Ω
Turn-Off Fall Time	t _f	-	13	-	ns	

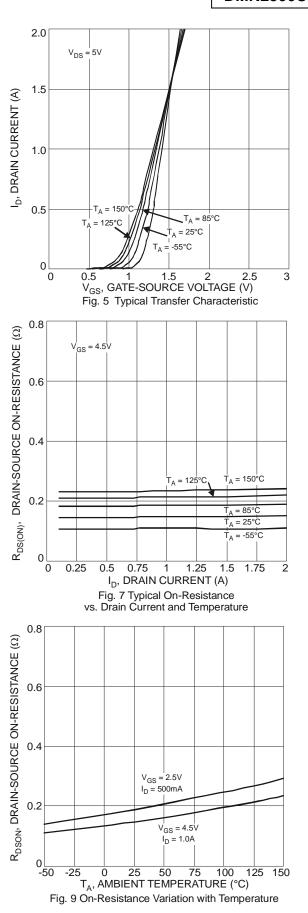
Notes: 7. Short duration pulse test used to minimize self-heating effect.



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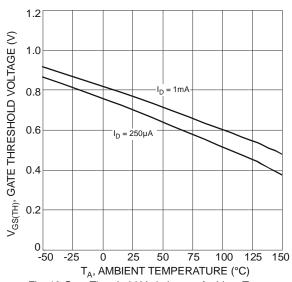


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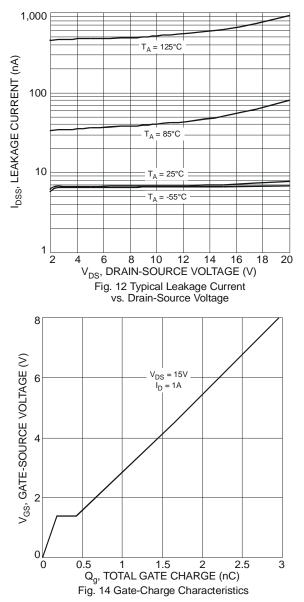




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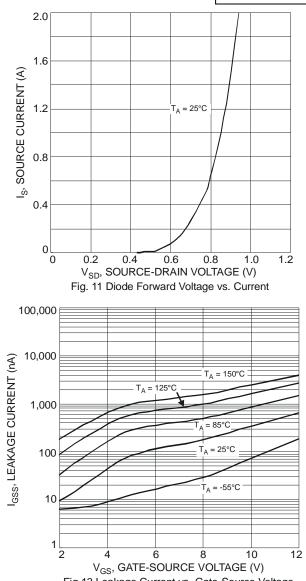
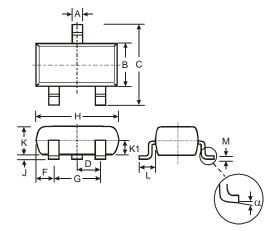


Fig.13 Leakage Current vs. Gate-Source Voltage



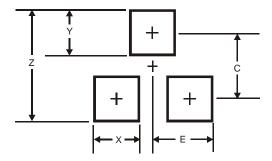


Package Outline Dimensions



	SOT23							
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
в	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
κ	0.903	1.10	1.00					
K1	-	-	0.400					
L	0.45	0.61	0.55					
М	0.085	0.18	0.11					
α	0°	8°	-					
All	Dimens	ions in	mm					

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35





DMN2300U

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